

DS26F32MQML Quad Differential Line Receivers

Check for Samples: DS26F32MQML

FEATURES

- Input Voltage Range of ±7.0V (Differential or Common Mode) ±0.2V Sensitivity over the Input Voltage Range
- High Input Impedance
- Operation from Single +5.0V Supply
- Input Pull-Down Resistor Prevents Output Oscillation on Unused Channels
- TRI-STATE Outputs, with Choice of Complementary Enables, for Receiving Directly onto a Data Bus

DESCRIPTION

The DS26F32 is a quad differential line receiver designed to meet the requirements of EIA Standards RS-422 and RS-423, and Federal Standards 1020 and 1030 for balanced and unbalanced digital data transmission.

The DS26F32 offers improved performance due to the use of state-of-the-art L-FAST bipolar technology. The L-FAST technology allows for higher speeds and lower currents by utilizing extremely short gate delay times. Thus, the DS26F32 features lower power, extended temperature range, and improved specifications.

The device features an input sensitivity of 200 mV over the input common mode range of ±7.0V. The DS26F32 provides an enable function common to all four receivers and TRI-STATE outputs with 8.0 mA sink capability. Also, a fail-safe input/output relationship keeps the outputs high when the inputs are open.

The DS26F32 offers optimum performance when used with the DS26F31 Quad Differential Line Driver.

A

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Connection Diagrams

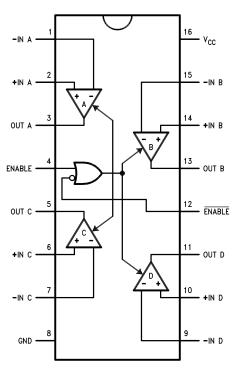


Figure 1. 16-Lead CDIP Package-Top View See Package Number NAC0016A, NFE0016A, or NAD0016A

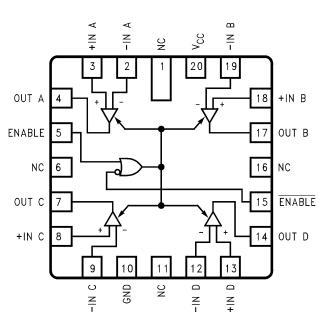


Figure 2. 20-Lead LCCC Package-Top View See Package Number NAJ0020A

Table 1. Function Table (Each Receiver)(1)

Differential Inputs	Ena	bles	Outputs
$V_{ID} = (V_{I} +) - (V_{I} -)$	Е	Ē	OUT
V _{ID} ≥ 0.2V	Н	Х	Н
	X	L	Н
V _{ID} ≤ −0.2V	Н	X	L
	Х	L	L
X	L	Н	Z

(1) H = High Level L = Low Level X = Immaterial



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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Absolute Maximum Ratings (1)

Storage Temperature Range	-65°C ≤ T _A ≤ +150°C
Operating Temperature Range	-55°C ≤ T _A ≤ +125°C
Lead Temperature (soldering, 60 sec)	300°C
Supply Voltage	7.0V
Common Mode Voltage Range	±25V
Differential Input Voltage	±25V
Enable Voltage	7.0V
Output Sink Current	50 mA
Maximum Power Dissipation (P _{D max} at 25°C) (2), (3)	500 mW
Thermal Resistance	
$ heta_{JA}$	
NFE0016A package	100°C/W
NAD0016A package	142°C/W
NAJ0020A package	87°C/W
θ_{JC}	
Junction-to- case	See MIL-STD-1835

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not verify specific performance limits. For verified specifications and test conditions, see the Electrical Characteristics. The verified specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) Derate J package 10.0mW/°C above +25°C, derate W package 7.1mW/°C above +25°C, derate E package 11.5mW/°C above +25°C.
- (3) Power dissipation must be externally controlled at elevated temperatures.

Recommended Operating Range

Operating Temperature	-55°C ≤ T _A ≤ +125°C
Supply Voltage	4.5V to 5.5V

Table 2. Radiation Features

DS26F32MJRQMLV	100 krads (Si)
DS26F32MWRQMLV	100 krads (Si)
DS26F32MWGRQMLV	100 krads (Si)

Table 3. Quality Conformance Inspection Mil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

Product Folder Links: DS26F32MQML



DS26F32 Electrical Characteristics DC Parameters

The following conditions apply, unless otherwise specified.

DC: $V_{CC} = 5V^{(1)}$

Parameter		Test Conditions	Notes	Min	Max	Units	Sub- groups
I _{In}	Input Current	Pin under test $V_{CC} = 4.5V$, $V_I = 15V$ Other inputs -15V $\leq V_I \leq +15V$			2.3	mA	1, 2, 3
		Pin under test $V_{CC} = 5.5V$, $V_I = -15V$ Other inputs $-15V \le V_I \le +15V$			-2.8	mA	1, 2, 3
I _{IL}	Logical "0" Enable Current	$V_{CC} = 5.5V, V_{En} = 0.4V$			-360	μA	1, 2, 3
I _{IH}	Logical "1" Enable Current	V _{CC} = 5.5V, V _I = 2.7V			10	μA	1, 2, 3
I _I	Logical "1" Enable Current	V _{CC} = 5.5V, V _I = 5.5V			50	μA	1, 2, 3
V _{IK}	Input Clamp Voltage (Enable)	V _{CC} = 4.5V, I _I = -18mA			-1.5	V	1, 2, 3
V _{OH}	Logical "1" Output Voltage	$V_{CC} = 4.5V, \underline{I}_{OH} = -440\mu A, \\ \Delta V_{I} = 1V, VEn = .8 = V_{En}$		2.5		V	1, 2, 3
V _{OL}	Logical "0" Output Voltage	$V_{CC} = 4.5V, V\overline{En} = 0.8V = V_{En},$ $I_{OL} = 4mA, \Delta V_{I} = -1V$			0.4	V	1, 2, 3
		$V_{CC} = 4.5V$, $V\overline{En} = 8V = V_{En}$, $I_{OL} = 8mA$, $\Delta V_I = -1V$.45	V	1, 2, 3
I _{CC}	Supply Current	$V_{CC} = 5.5 \underline{V}$, All $V_I = Gnd$, $V_{En} = 0V$, $\overline{V_{En}} = 2V$			50	mA	1, 2, 3
l _{OZ}	Off-State Output Current	$V_{CC} = 5.5V, V_{O} = 0.4V, V_{En} = 0.8V, V_{En} = 2V$			-20	μΑ	1, 2, 3
		$V_{CC} = 5.5V, V_O = 2.4V, V_{En} = 0.8V, V_{En} = 2V$			20	μΑ	1, 2, 3
R _I	Input Resistance	-15 ≤ V _{CM} ≤ 15V		14		ΚΩ	1, 2, 3
V_{Th}	Differential Input Voltage	$V_{CC} = 4.5V$, $V_{OUT} = V_{OL}$ or V_{OH} $-7V \le V_{CM} \le 7V$, $V_{En} = \overline{V_{En}} = 2.5V$	(2)	-0.2	0.2	V	1, 2, 3
		$V_{CC} = 5.5V$, $V_{OUT} = V_{OL}$ or V_{OH} -7V $\leq V_{CM} \leq 7V$, $V_{En} = V_{En} = 2.5V$	(2)	-0.2	0.2	V	1, 2, 3
V _{IL}	Logical "0" Input Voltage (Enable)	V _{CC} = 5.5V	(2)		0.8	V	1, 2, 3
V _{IH}	Logical "1" Input Voltage (Enable)	V _{CC} = 4.5V	(2)	2.0		V	1, 2, 3
I _{SC Min}	Output Short Circuit Current	$V_{CC} = 4.5V, V_{O} = 0V,$ $\Delta V_{I} = 1V$		-15		mA	1, 2, 3
I _{SC Max}	Output Short Circuit Current	$V_{CC} = 5.5V, V_{O} = 0V,$ $\Delta V_{I} = 1V$			-85	mA	1, 2, 3

⁽¹⁾ Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are specified only for the conditions as specified in Mil-Std-883, Method 1019.5, Condition A

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⁽²⁾ Parameter tested go-no-go only.



DS26F32 Electrical Characteristics AC Parameters

The following conditions apply, unless otherwise specified.

AC: $V_{CC} = 5V$ (1)

	Parameter	Test Conditions	Notes	Min	Max	Units	Sub- groups
t _{PLH}		C _L = 50pF	(2)		23	nS	9
			(2)		31	nS	10, 11
		C _L = 15pF	(3)		22	nS	9
			(3)		30	nS	10, 11
t _{PHL}		C _L = 50pF	(2)		23	nS	9
			(2)		31	nS	10, 11
		C _L = 15pF	(3)		22	nS	9
			(3)		30	nS	10, 11
t _{PZH}	Enable Time	C _L = 50pF	(2)		18	nS	9
			(2)		29	nS	10, 11
		C _L = 15pF	(3)		16	nS	9
			(3)		27	nS	10, 11
t _{PZL}	Enable Time	C _L = 50pF	(2)		20	nS	9
			(2)		29	nS	10, 11
		C _L = 15pF	(3)		18	nS	9
			(3)		27	nS	10, 11
t _{PHZ}	Disable Time	C _L = 50pF	(2)		55	nS	9
			(2)		62	nS	10, 11
		$C_L = 5pF$	(3)		20	nS	9
			(3)		27	nS	10, 11
t _{PLZ}	Disable Time	C _L = 50pF	(2)		30	nS	9
			(2)		42	nS	10, 11
		C _L = 5pF	(3)		18	nS	9
			(3)		30	nS	10, 11

⁽¹⁾ Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are specified only for the conditions as specified in Mil-Std-883, Method 1019.5, Condition A

DS26F32 Electrical Characteristics DC Drift Parameters

This section applies to -QMLV devices only. Devices shall be read & recorded at $T_A = 25^{\circ}\text{C}$ before and after each burn-in and shall not change by more than the limits indicated. The delta rejects shall be included in the PDA calculation.

	Parameter	Test Conditions	Notes	Min	Max	Units	Sub- groups
V_{OH}	Logical "1" Output Voltage	$V_{CC} = 4.5V, I_{OH} = -440\mu A,$ $\Delta V_{I} = 1V, VEn = 0.8V = V_{En}$		-250	250	mV	1
V _{OL}	Logical "0" Output Voltage	$V_{CC} = 4.5V, I_{OL} = 4mA,$ $\Delta V_{I} = -1V, VEn = 0.8V = V_{En}$		-45	45	mV	1
		$V_{CC} = 4.5 \text{V}, I_{\underline{OL}} = 8 \text{mA}, \\ \Delta V_{I} = -1 \text{V}, VEn = 0.8 \text{V} = V_{En}$		-45	45	mV	1
I _I	Input Current	Pin under test $V_{CC} = 4.5V$, $V_{I} = 15V$ Other inputs -15V $\leq V_{I} \leq +15V$		-0.28	0.28	mA	1
		Pin under test $V_{CC} = 5.5V$, $V_I = -15V$ Other inputs $-15V \le V_I \le +15V$		-0.28	0.28	mA	1

Product Folder Links: DS26F32MQML

⁽²⁾ Tested at 50pF, system capacitance exceeds 5pF to 15pF.

⁽³⁾ Tested at 50pF specifies limit at 15pF & 5pF.



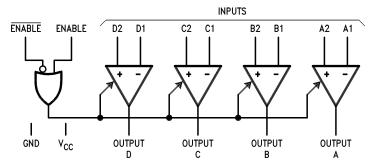
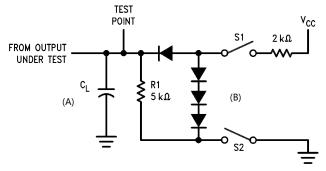


Figure 3. Logic Symbol



C L includes probe and jig capacitance.

- A. Parameter tested go-no-go only.
- B. Tested at 50pF specifies limit at 15pF and 5pF.

Figure 4. Load Test Circuit for Three-State Outputs

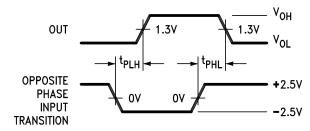


Diagram shown for ENABLE Low.

S1 and S2 of Load Circuit are closed except where shown.

Pulse Generator of all Pulses: Rate \leq 1.0 MHz, $Z_O = 50\Omega$, $t_f \leq$ 6.0 ns, $t_f \leq$ 6.0 ns.

Figure 5. Propagation Delay

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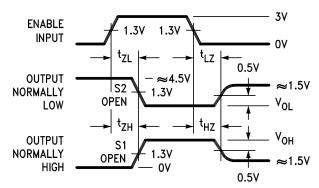


Diagram shown for $\overline{\text{ENABLE}}$ Low.

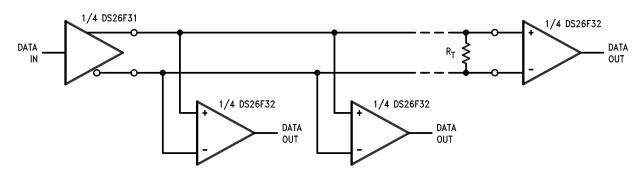
S1 and S2 of Load Circuit are closed except where shown.

Pulse Generator of all Pulses: Rate \leq 1.0 MHz, Z_O = 50 Ω , $t_r \leq$ 6.0 ns, $t_f \leq$ 6.0 ns.

All diodes are IN916 or IN3064.

Figure 6. Enable and Disable Times

TYPICAL APPLICATION



Product Folder Links: DS26F32MQML



REVISION HISTORY

Released	Revision	Section	Originator	Changes
3/01/06	*	New Release, Corporate format	L. Lytle	1 MDS data sheet converted into one Corp. data sheet format. MNDS26F32M-X-RH Rev 0C0 will be archived.
4/15/2013	А		TIS	Changed layout of National Data Sheet to TI format

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
5962-7802005M2A	Active	Production	LCCC (NAJ) 20	50 TUBE	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	DS26F32ME/ 883 Q 5962-78020 05M2A ACO 05M2A >T
5962-7802005MFA	Active	Production	CFP (NAD) 16	19 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	DS26F32MW /883 Q 5962-78020 05MFA ACO 05MFA >T
5962R7802005VEA	Active	Production	CDIP (NFE) 16	25 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	DS26F32MJRQMLV 5962R7802005VEA Q
5962R7802005VFA	Active	Production	CFP (NAD) 16	19 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	DS26F32MWR QMLV Q 5962R78020 05VFA ACO 05VFA >T
DS26F32 MW8	Active	Production	WAFERSALE (YS) 0	1 OTHER	-	Call TI	Level-1-NA-UNLIM	-55 to 125	
DS26F32ME/883	Active	Production	LCCC (NAJ) 20	50 TUBE	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	DS26F32ME/ 883 Q 5962-78020 05M2A ACO 05M2A >T
DS26F32MJRQMLV	Active	Production	CDIP (NFE) 16	25 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	DS26F32MJRQMLV 5962R7802005VEA Q
DS26F32MJRQMLV.A	Active	Production	CDIP (NFE) 16	25 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	DS26F32MJRQMLV 5962R7802005VEA Q
DS26F32MW/883	Active	Production	CFP (NAD) 16	19 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	DS26F32MW /883 Q 5962-78020 05MFA ACO 05MFA >T

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Orderable part number	Status	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
DS26F32MWRQMLV	Active	Production	CFP (NAD) 16	19 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	DS26F32MWR QMLV Q 5962R78020 05VFA ACO 05VFA >T
DS26F32MWRQMLV.A	Active	Production	CFP (NAD) 16	19 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	DS26F32MWR QMLV Q 5962R78020 05VFA ACO 05VFA >T

⁽¹⁾ Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF DS26F32MQML, DS26F32MQML-SP:

Military : DS26F32MQML

• Space : DS26F32MQML-SP

NOTE: Qualified Version Definitions:

- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

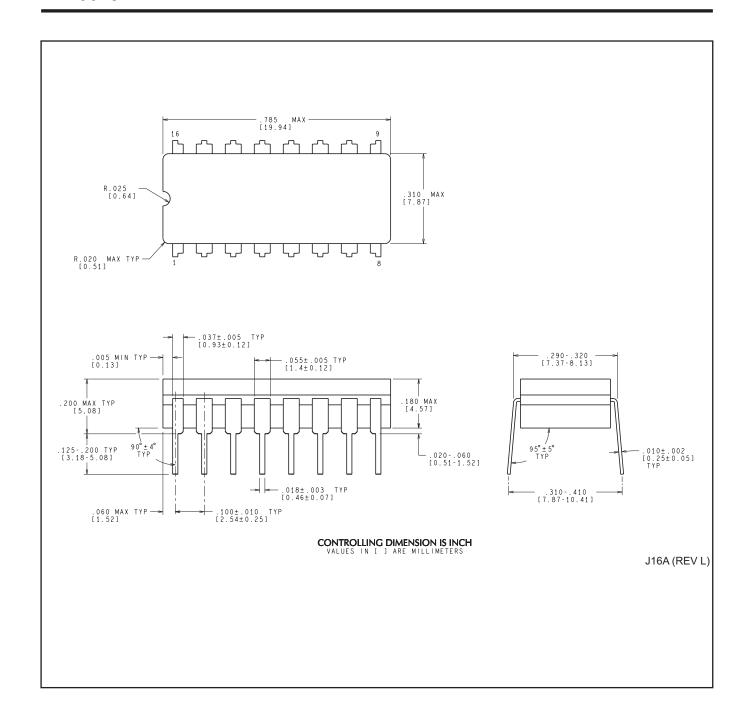
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TUBE

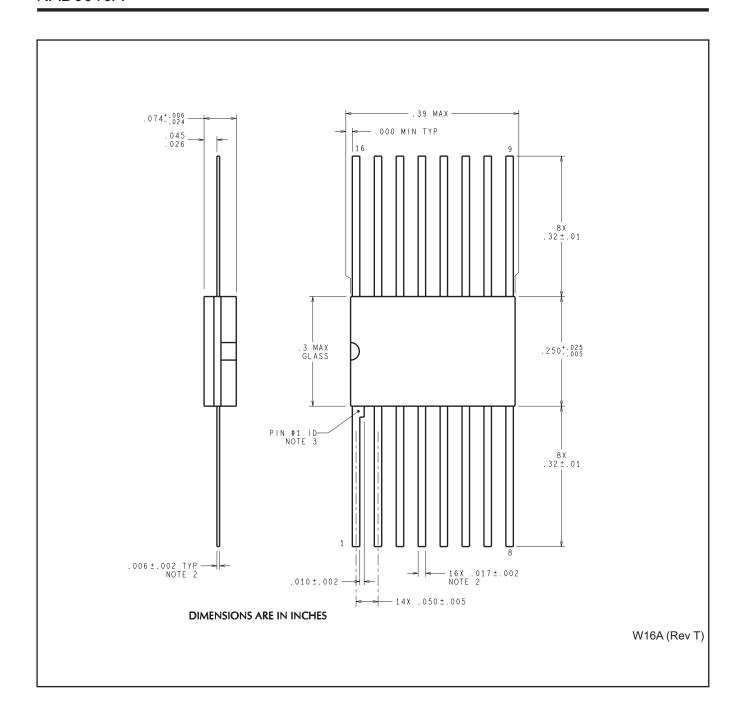


*All dimensions are nominal

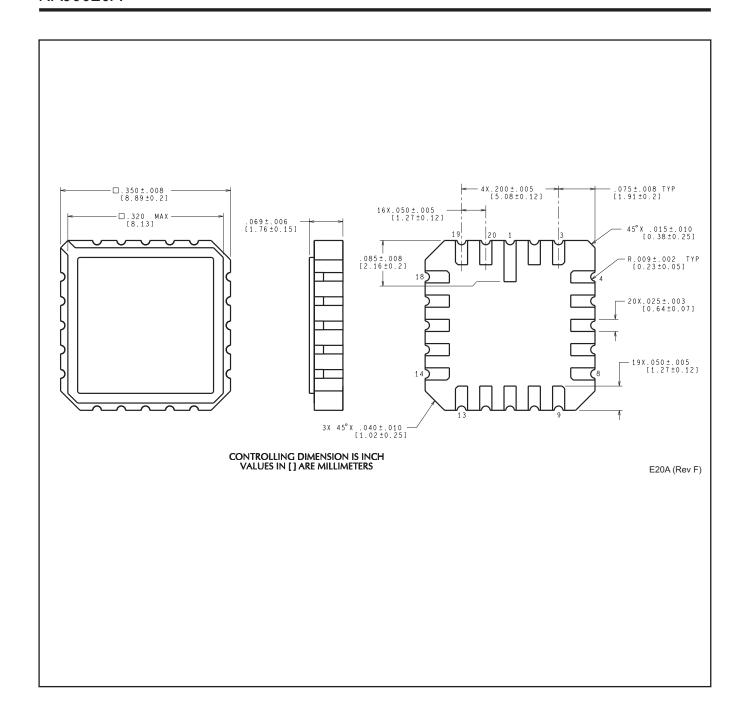
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-7802005M2A	NAJ	LCCC	20	50	470	11	3810	0
5962-7802005MFA	NAD	CFP	16	19	502	23	9398	9.78
5962R7802005VEA	NFE	CDIP	16	25	506.98	15.24	13440	NA
5962R7802005VFA	NAD	CFP	16	19	502	23	9398	9.78
DS26F32ME/883	NAJ	LCCC	20	50	470	11	3810	0
DS26F32MJRQMLV	NFE	CDIP	16	25	506.98	15.24	13440	NA
DS26F32MJRQMLV.A	NFE	CDIP	16	25	506.98	15.24	13440	NA
DS26F32MW/883	NAD	CFP	16	19	502	23	9398	9.78
DS26F32MWRQMLV	NAD	CFP	16	19	502	23	9398	9.78
DS26F32MWRQMLV.A	NAD	CFP	16	19	502	23	9398	9.78











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